NSN 5961-01-310-2001

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-310-2001 **Inclosure Material:** Plastic **Overall Length:** 1.970 inches **Terminal Length:** 0.420 inches **Overall Height:** 0.590 inches **Overall Width:** 1.255 inches **Component Name And Quantity:** 2 semiconductor device thyristor **Mounting Method: Terminal Semiconductor Material:** Silicon all semiconductor device thyristor **Voltage Rating In Volts Per Characteristic:** 320.0 forward voltage, dc all semiconductor device thyristor **Current Rating Per Characteristic:** 25.00 amperes forward current, average absolute all semiconductor device thyristor **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector blank all semiconductor device thyristor **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** All semiconductor deivce thyristor junction pattern arrangement: pnpn **Terminal Type And Quantity:** 6 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:**